# PC450T11

### Features

- 1. Built-in breakdown diode for absorption of surge voltage
- 2. High current transfer ratio (CTR: MIN. 1 500% at  $I_F = 5mA$ )
- 3. Mini-flat package
- 4. Applicable to soldering reflow
- 5. Available tape-packaged products

# Applications

1. Programmable controllers

# Package Specifications

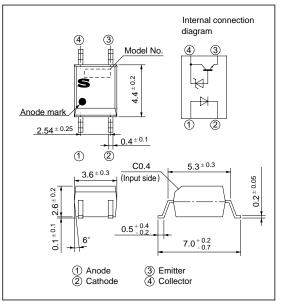
Model No.	Package Specification
PC450T11	Taping diameter 178mm(750pcs.)

# Photocoupler with Built-in Breakdown Diode for Surge Voltage Absorption

#### Outline Dimensions

 $(T_{2} - 25^{\circ}C)$ 

(Unit:mm)



#### Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit				
Forward current	I <sub>F</sub>	50	mA				
*1Peak forward current	I <sub>FM</sub>	1	Α				
Reverse voltage	VR	6	V				
Power dissipation	Р	70	mW				
Emitter-collector voltage	V ECO	6	V				
*2Surge endurance	Esj	20	mJ				
Collector current	Ic	150	mA				
Collector power dissipation	Pc	150	mW				
Total power dissipation	P tot	170	mW				
*3 Isolation voltage		3.75	kV rms				
Operating temperature		- 30 to + 100	°C				
Storage temperature		- 40 to + 125	°C				
<sup>*4</sup> Soldering temperature		260	°C				
	Parameter   Forward current   *1Peak forward current   Reverse voltage   Power dissipation   Emitter-collector voltage   *2Surge endurance   Collector current   Collector power dissipation   Total power dissipation   *3 Isolation voltage   Operating temperature   Storage temperature	ParameterSymbolForward current $I_F$ *1Peak forward current $IFM$ Reverse voltage $V_R$ Power dissipationPEmitter-collector voltage $V_{ECO}$ *2Surge endurance $E_{sj}$ Collector current $Ic$ Collector power dissipation $P_{tot}$ *3 Isolation voltage $V_{iso}$ Operating temperature $T_{opr}$ Storage temperature $T_{stg}$	ParameterSymbolRatingForward currentIF50*1Peak forward currentIFM1Reverse voltageVR6Power dissipationP70Emitter-collector voltageVECO6*2Surge enduranceEsj20Collector currentIC150Collector power dissipationPc150Total power dissipationPtot170*3 Isolation voltageViso3.75Operating temperatureTopr- 30 to + 100Storage temperatureTstg- 40 to + 125				

\*1 Pulse width <=100  $\mu s,$  Duty ratio : 0.001

\*2 Esj = 40V ( $V_{CEO}$ ) x 100mA( $I_C$ ) x 10ms x 1/2

\*3 AC for 1 min., 40 to 60% RH, f = 60Hz

\*4 For 10 seconds

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# Electro-optical Characteristics

 $(Ta = 25^{\circ}C)$ 

							(	/
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward volta	ge	VF	$I_F = 20 m A$	-	1.2	1.4	V
	Reverse curren	nt	IR	$V_R = 4V$	-	-	10	μA
	Terminal capa	citance	Ct	V = 0, f = 1 kHz	-	30	250	pF
Output	Collector dark current		ICEO	$V_{CE} = 20V, I_F = 0$	-	-	5	μA
	Collector-emit breakdown vo		BV <sub>CEO</sub>	$\begin{array}{l} I_F=0\\ I_C=0.1mA \end{array}$	40	-	60	V
	Emitter-collec breakdown vo		BV <sub>ECO</sub>	$I_{E} = 10  \mu \text{ A}, I_{F} = 0$	6	-	-	v
	Collector curr	ent	Ic	$V_{CE} = 2V, I_F = 5mA$	75	-	-	mA
Transfer charac- teristics	Collector-emit saturation volt		V <sub>CE(sat)</sub>	$\begin{array}{l} I_F = 10 mA \\ I_C = 100 mA \end{array}$	-	-	0.5	v
	Isolation resistance		R iso	DC500V, 40 to 60% RH	5 x 10 <sup>10</sup>	1011	-	Ω
	Floating capacitance		Cf	V = 0, $f = 1MHz$	-	0.6	1.0	pF
	Response time	Rise time	tr	$V_{CE} = 2V, I_C = 2mA$	-	50	-	μs
		Fall time	tf	$R_{\rm L} = 100\Omega$	-	30	-	μs

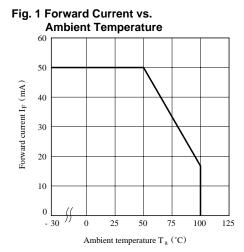


Fig. 2 Diode Power Dissipation vs. Ambient Temperature

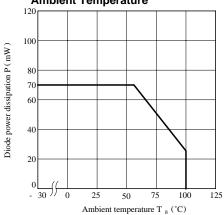


Fig. 3 Power Dissipation vs. Ambient Temperature

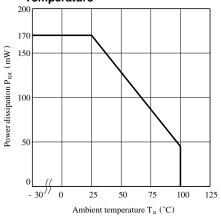
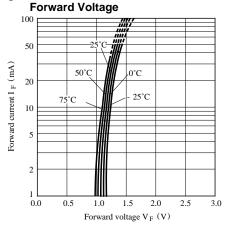
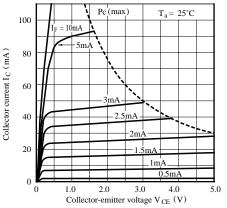


Fig. 5 Forward Current vs.







#### Fig. 4 Peak Forward Current vs. Duty Ratio

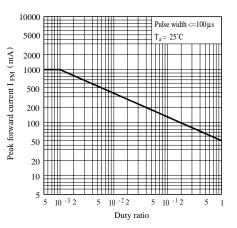


Fig. 6 Current Tranfer Ratio vs. Forward Current

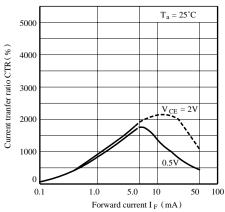
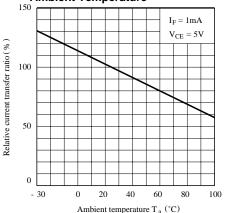


Fig. 8 Relative Current Transfer Ratio vs. Ambient Temperature



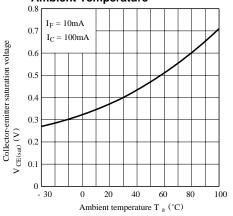
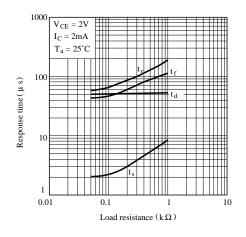


Fig.9 Collector-emitter Saturation Voltage vs. Ambient Temperature

Fig.11 Response Time vs. Load Resistance



•Please refer to the chapter "Precautions for Use."



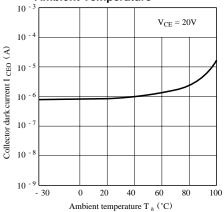
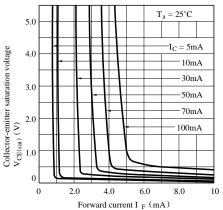


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



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